PCN Number: 20160421001 4/27/2016 PCN Date: Qualification of AIZU as an additional Wafer Fab Site option for select devices in F05 and Title: **HPA07** Technology **Customer Contact:** PCN Manager Dept: **Quality Services Estimated Sample** Date provided at sample **Proposed 1st Ship Date:** 7/27/2016 **Availability:** request. **Change Type:** Assembly Site **Assembly Process Assembly Materials Electrical Specification Mechanical Specification** Design **Test Site** Packing/Shipping/Labeling Test Process Wafer Bump Process Wafer Bump Site Wafer Bump Material Wafer Fab Site Wafer Fab Materials Wafer Fab Process Part number change

PCN Details

Description of Change:

Texas Instruments is pleased to announce the qualification of its AIZU fabrication facility as an additional Wafer Fab source for the selected devices listed in "Product Affected" section.

	Current Sites		Additional Sites		
Current Fab Site	Process	Wafer Diameter	Additional Fab Site	Process	Wafer Diameter
DP1DM5	F05	200mm	AIZU	F05	200mm
DP1DM5	HPA07	200mm	AIZU	HPA07	200mm

Qual details are provided in the Qual Data Section.

Reason for Change:

Continuity of Supply

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

Changes to product identification resulting from this PCN:

Current

Chip Site	Chip Site Origin (20L)	Chip Site Country Code (21L)	Chip Site City
DP1DM5	DM5	USA	Richardson

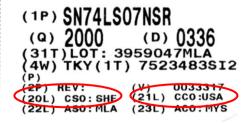
New Fab Site

Chip Site	Chip Site Origin (20L)	Chip Site Country Code (21L)	Chip Site City
AIZU	CU2	JPN	Aizuwakamatsu-shi

Sample product shipping label (not actual product label)







Product Affected Group:							
HPA02149AIYFFR	TMS320F28232ZJZS	TMS320F28235ZJZA	TMS320F28334ZHHA				
INA231AIYFFR	TMS320F28234PGFA	TMS320F28235ZJZS	TMS320F28334ZJZA				
INA231AIYFFT	TMS320F28234PTPS	TMS320F28332PGFA	TMS320F28334ZJZS				
PLCF28335PGFA	TMS320F28234ZHHA	TMS320F28332PTPS	TMS320F28335PGFA				
SN2835PGFA	TMS320F28234ZJZA	TMS320F28332ZHHA	TMS320F28335PTPS				
TMS320F28232PGFA	TMS320F28234ZJZS	TMS320F28332ZJZA	TMS320F28335ZHHA				
TMS320F28232PTPS	TMS320F28235PGFA	TMS320F28332ZJZS	TMS320F28335ZJZA				
TMS320F28232ZHHA	TMS320F28235PTPS	TMS320F28334PGFA	TMS320F28335ZJZS				
TMS320F28232ZJZA	TMS320F28235ZHHA	TMS320F28334PTPS					

Qualification Report

INA231AIYFFR/T in AIZU as 2nd source Approve Date 8-April-2016

Product Attributes

Attributes	Qual Device: INA231AIYFF	QBS Process Reference: CD3246B0YFFR	QBS Process Reference: TMP103AYFF	QBS Process Reference: TSC2014YZG	QBS Package Reference: CD3246B0YFFR	QBS Package Reference: TPS75105YFF
Assembly Site	CLARK-AT	CLARK-AT	CLARK-AT	CLARK-AT	CLARK-AT	CLARK-AT
Package Family	DSBGA	DSBGA	DSBGA	DSBGA	DSBGA	DSBGA
Wafer Fab Supplier	AIZU	AIZU	AIZU	AIZU	DMOS5	FFAB
Wafer Process	50HPA07HV	50HPA07HV	33HPA07	33HPA07	50HPA07HV	3370A12

Process

- QBS: Qual by Similarity
- Qual Device INA231AIYFF is qualified at LEVEL1-260C

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: INA231AIYFF	QBS Process Reference: CD3246B0YFFR	QBS Process Reference: TMP103AYFF	QBS Process Reference: TSC2014YZG	QBS Package Reference: CD3246B0YFFR	QBS Package Reference: TPS75105YFF
ED	Electrical Characterization	Per Datasheet Parameters	Pass	Pass	Pass	Pass	Pass	Pass
HAST	Biased HAST, 130C/85%RH	96 Hours	-	3/252/0	-	-	3/231/0	3/230/0
HBM	ESD - HBM	2500 V	1/3/0	2/12/0	1/3/0	1/3/0	2/12/0	-
CDM	ESD - CDM	1000 V	1/3/0	2/6/0	1/3/0	-	2/6/0	-
HTOL	Life Test, 150C	300 Hours	1/77/0	3/231/0	-	1/77/0	3/231/0	3/231/0
HTSL	High Temp. StorageBake, 170C	420 Hours	-	3/231/0	-	-	3/231/0	3/231/0
LU	Latch-up	(per JESD78)	1/6/0	3/18/0	1/6/0	1/6/0	3/18/0	-
PD	Physical Dimensions		-	-	-	-	-	3/15/0
SBS	Bump Shear	Unstressed	-	3/150/0	-	-	-	3/150/0
TC	Temperature Cycle, -40/125C	400 Cycles		-	-	-	3/230/0	-
TC	Temperature Cycle, -55/125C	700 Cycles	-	3/231/0	-	-	-	3/231/0
UHAST	Unbiased HAST, 130C/85%RH	96 Hours	-	3/231/0	-	-	3/231/0	3/231/0

⁻ The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/490 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV: 155C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47: 55C/125C/100 Cycles and -55C/150C/30 Cycles
- Quality and Environmental data is available at T's external Web site: http://www.ti.com/

Green/Pb-free Status: Qualified Pb-Free (SMT) and Green

Qualification Data: Aizu F05 Qualification (Approved 4/14/2016)

This qualification has been specifically developed for the validation of this change. The qualification data

validates that the proposed change meets the applicable released technical specifications. **Qualification Device Construction Details:** Qualification Vehicle: TMS320F2803XAPN Wafer Fab Site: **AIZU** Wafer Process: F05 Assembly Site: Wafer Size Dia. 200mm TI Philippines ☐ Test Results **Qualification:** Plan Sample Size Reliability Test Conditions (PASS/FAIL) 20K Write / Erase Cycles prior to 20K W/E 1800/0 HTSL, HTOL, RTSL HTOL (High Temperature Op Life) 125C - 1000 Hours 231/0 HTSL (High Temp Storage Life)* 150C Bake - 1000 Hours 231/0 RTSL (Room Temp Storage Life) 231/0 25C - 1000 Hours Package Reliability

Preconditioning	MSL3/260C	693/0
THB	85C/85RH	231/0
Temp Cycle	-65C/150C 500 Cycles	231/0
Autoclave	121C/96hrs	231/0
ESD-HBM	2000v	15/0
ESD-CDM	750v	6/0
Latchup	1.5Vdd +/-100mA 125C	6/0

Notes:

Qualification tests "pass" on zero fails for each test <optional> "QBS" stands for Qualification by Similarity

For questions regarding this notice, e-mails can be sent to the regional contacts shown below, or you can contact your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
Japan	PCNJapanContact@list.ti.com

^{*} Test requires Moisture Preconditioning